imall

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Switch-mode Soft Recovery Power Rectifier

These state-of-the-art devices are designed for boost converter or hard-switched converter applications, especially for Power Factor Correction application. It could also be used as a free wheeling diode in variable speed motor control applications and switching mode power supplies.

Features

- Soft Recovery with Low Reverse Recovery Charge (Q_{RR}) and Peak Reverse Recovery Current (I_{RRM})
- Epoxy meets UL 94 V-0 @ 0.125 in
- Low Forward Voltage
- Low Leakage Current
- High Temperature Glass Passivated Junction
- These are Pb–Free Devices

Mechanical Characteristics:

- Case: Epoxy, Molded
- Weight: 1.9 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	600	V
Average Rectified Forward Current (At Rated V_R , T_C = 125°C)	Ι _Ο	15	А
Peak Repetitive Forward Current (At Rated V_R , Square Wave, 20 kHz,T _C = 125°C)	I _{FRM}	30	A
Non-Repetitive Peak Surge Current (Surge applied at rated load conditions, halfwave, single phase, 60 Hz)	I _{FSM}	100	A
Operating Junction and Storage Temperature Range	T _J , T _{stg}	-65 to +150	°C

THERMAL CHARACTERISTICS

Parameter	Symbol	Value	Unit
MSR1560G: Thermal Resistance Junction-to-Case Junction-to-Ambient	${\sf R}_{ heta { m JC}} \ {\sf R}_{ heta { m JA}}$	1.6 72.8	°C/W
MSRF1560G: Thermal Resistance Junction-to-Case Junction-to-Ambient	$R_{ extsf{ heta}JC} \ R_{ heta}JA$	4.25 75	°C/W

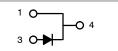
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

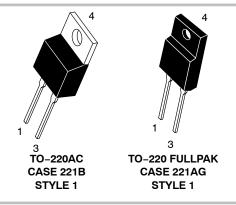


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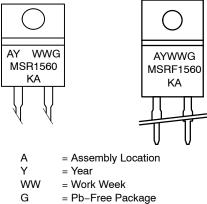
http://onsemi.com

SOFT RECOVERY POWER RECTIFIER 15 AMPERES, 600 VOLTS





MARKING DIAGRAMS



- KA = Diode Polarity

ORDERING INFORMATION

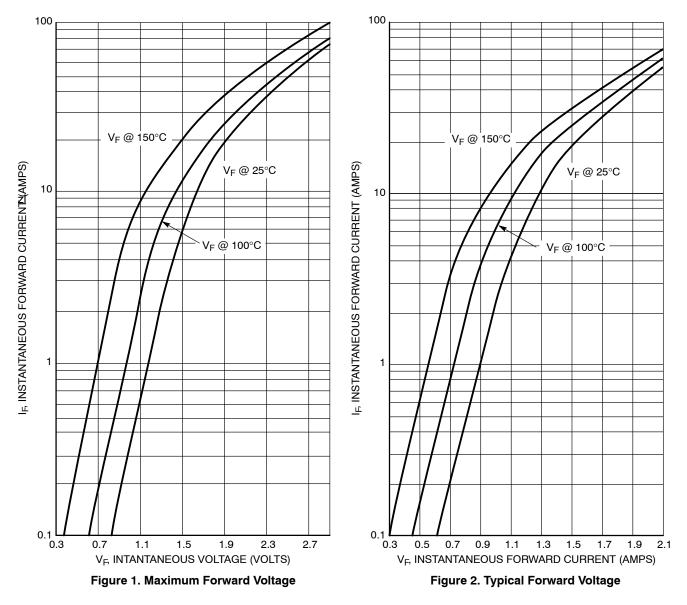
Device	Package	Shipping
MSR1560G	TO-220AC (Pb-Free)	50 Units/Rail
MSRF1560G	TO-220FP (Pb-Free)	50 Units/Rail

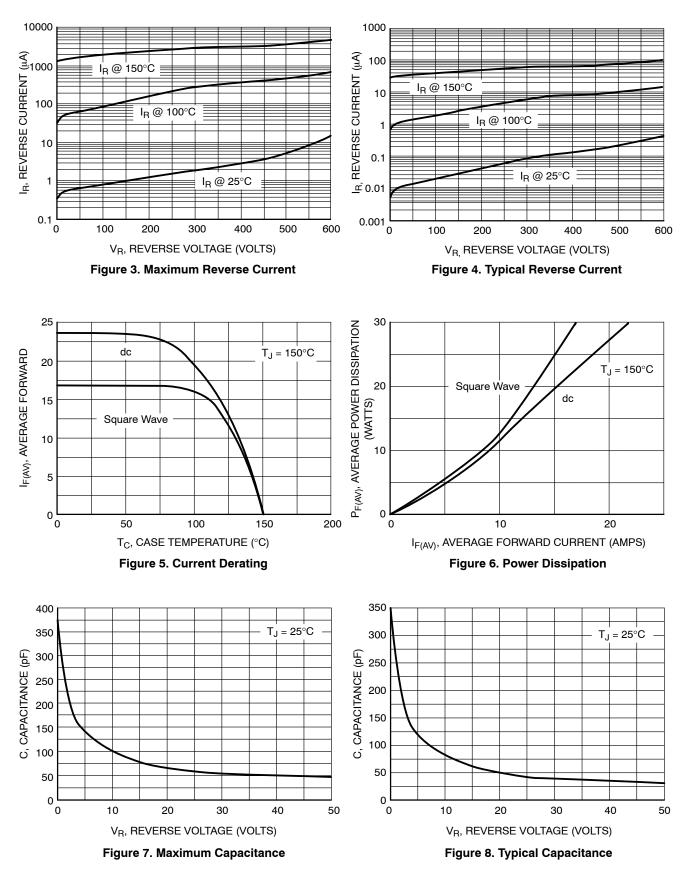
ELECTRICAL CHARACTERISTICS

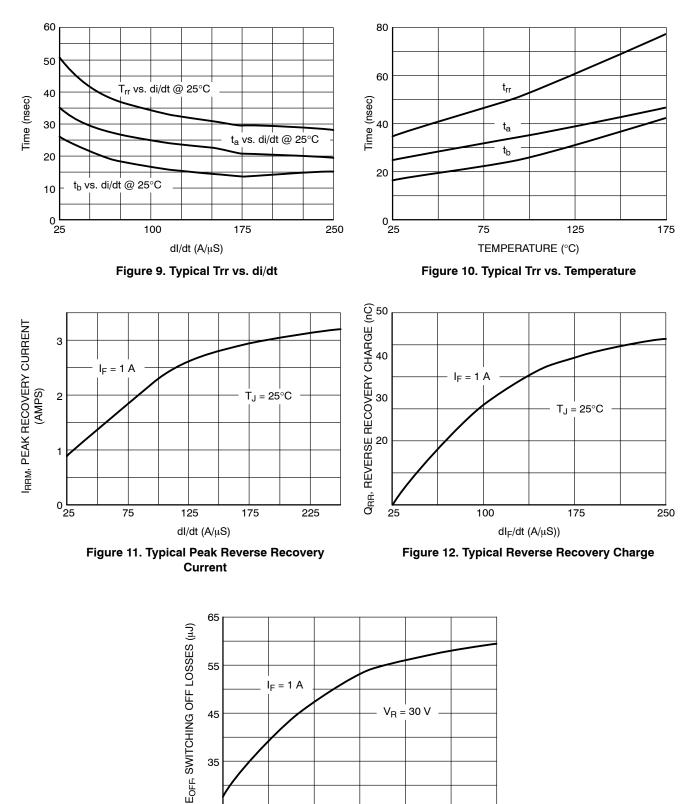
Characteristic	Symbol	Va	lue	Unit
Instantaneous Forward Voltage (Note 1) (I _F = 15 A)	V _F	T _J = 25°C	T _J = 150°C	V
Maximum Typical		1.8 1.5	1.4 1.2	
Instantaneous Reverse Current (V _R = 600 V)	I _R	T _J = 25°C	T _J = 150°C	μA
Maximum Typical		15 0.4	5000 100	
Reverse Recovery Time (Note 2) (V _R = 30 V, I _F = 1 A, di/dt = 100 A/ μ s)	t _{rr}	T _J = 25°C	T _J = 100°C	ns
Maximum Typical		45 35	65 54	
Typical Recovery Softness Factor (V_R = 30 V, I_F = 1 A, di/dt = 100 A/ μ s)	s = t _b /t _a	0.67	0.74	
Typical Peak Reverse Recovery Current (V _R = 30 V, I _F = 1 A, di/dt = 100 A/ μ s)	I _{RRM}	2.3	3.2	А
Typical Reverse Recovery Charge (V _R = 30 V, I _F = 1 A, di/dt = 100 A/ μ s)	Q _{RR}	31	78	nC

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 1. Pulse Test: Pulse Width \leq 380 µs, Duty Cycle \leq 2%

2. T_{RR} measured projecting from 25% of I_{RRM} to zero current







 $dI_F/dt (A/\mu S)$ Figure 13. Typical Switching Off Losses

175

250

100

35

25 ⊾ 25

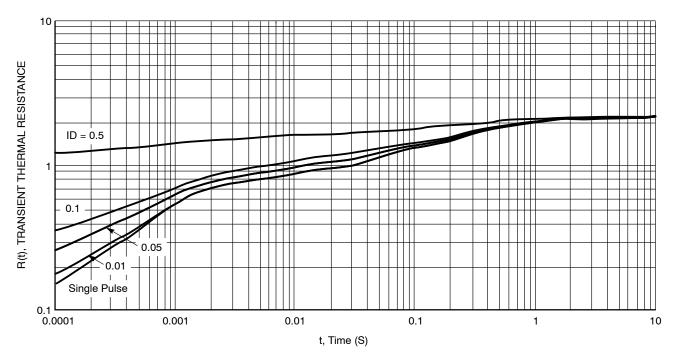


Figure 14. Transient Thermal Response

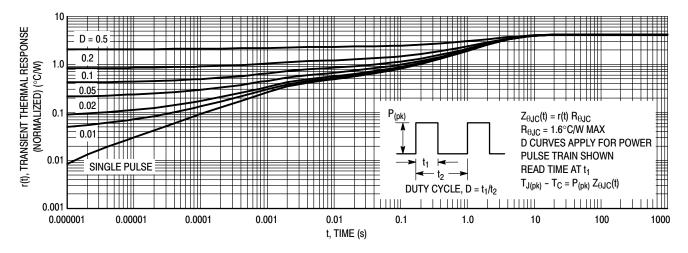


Figure 15. Thermal Response, (MSRF1560) Junction-to-Case ($R_{\theta JC}$)

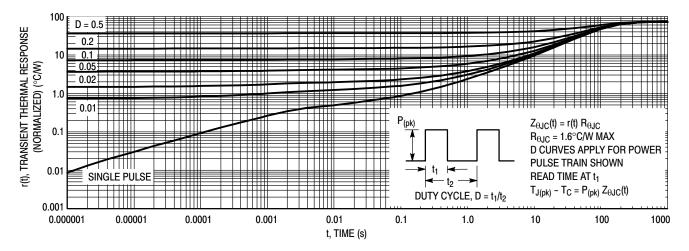
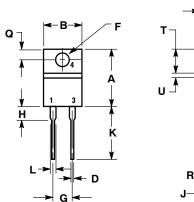


Figure 16. Thermal Response, (MSRF1560) Junction-to-Ambient ($R_{\theta JA}$)

PACKAGE DIMENSIONS

TO-220 TWO-LEAD CASE 221B-04 **ISSUE F**



Δ

D

▲ L1

3X b

E/2

₀₹

3X b2

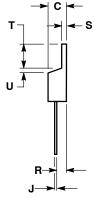
е e1 ⁴⊕

1 2 ØP

С

 \oplus 0.14 \otimes B A \otimes

⊕ 0.25 ^(M) B A ^(M) C



H1

С

NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI

Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.595	0.620	15.11	15.75	
В	0.380	0.405	9.65	10.29	
С	0.160	0.190	4.06	4.82	
D	0.025	0.039	0.64	1.00	
F	0.142	0.161	3.61	4.09	
G	0.190	0.210	4.83	5.33	
н	0.110	0.130	2.79	3.30	
J	0.014	0.025	0.36	0.64	
K	0.500	0.562	12.70	14.27	
L	0.045	0.060	1.14	1.52	
Q	0.100	0.120	2.54	3.04	ST۱
R	0.080	0.110	2.04	2.79	
S	0.045	0.055	1.14	1.39	
Т	0.235	0.255	5.97	6.48	
U	0.000	0.050	0.000	1.27	

'LE 1: PIN 1. CATHODE 2. N/A

3. ANODE 4. CATHODE

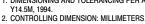
TO-220 FULLPAK. 2-LEAD CASE 221AG **ISSUE A**

NOTE 3

Δ2

STYLE 1: PIN 1. CATHODE N/A
 ANODE

NOTES: 1. DIMENSIONING AND TOLERANCING PER ASME



- CONTOUR UNCONTROLLED IN THIS AREA.
 DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH AND GATE PROTRUSIONS. MOLD FLASH AND GATE PROTRUSIONS NOT TO EXCEED 0.13 PER SIDE. THESE DIMENSIONS ARE TO BE MEASURED AT OUTERMOST EXTREME OF THE PLASTIC BODY. DIMENSION b2 DOES NOT INCLUDE DAMBAR
- 5 PROTRUSION. LEAD WIDTH INCLUDING PROTRUSION SHALL NOT EXCEED 2.00.

	MILLIMETERS		
DIM	MIN	MAX	
Α	4.30	4.70	
A1	2.50	2.90	
A2	2.50	2.90	
b	0.54	0.84	
b2	1.10	1.40	
C	0.49	0.79	
D	14.22	15.88	
E	9.65	10.67	
е	2.54 BSC		
e1	5.08 BSC		
H1	5.97	6.48	
L	12.70	14.73	
L1		2.80	
Р	3.00	3.40	
Q	2.80	3.20	

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